

isc N-Channel MOSFET Transistor

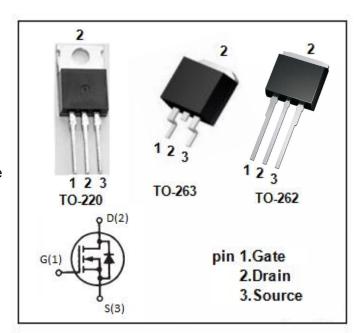
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DESCRIPTION

- Drain Current $-I_D$ = 80A@ T_C =25 $^{\circ}$ C
- Drain Source Voltage- V_{DSS}=75V(Min)
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- · High current switching applications
- DC-DC converter and motor drive applications



ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	75	V
V _{GS}	Gate-Source Voltage	±20	V
Ι _D	Drain Current-continuous@ T _C =25℃	80	А
І _{ОМ}	Drain Current-Single Pluse	320	А
P _{tot}	Total Dissipation@Tc=25°C	250	W
T _j	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	0.5	°C/W

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• ELECTRICAL CHARACTERISTICS (T_C=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0; I _D = 1mA	75	-	V
$V_{GS(TH)}$	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	2.1	4.0	V
R _{DS(ON)}	Drain-Source On-stage Resistance	V _{GS} = 10V; I _D = 66A	-	7.4	mΩ
I _{GSS}	Gate Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0	-	±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 75V, V _{GS} = 0V, T _J = 25°C	-	1	μA
V _{SD}	Diode Forward Voltage	I _S =80A; V _{GS} =0V	-	1.3	V

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